

GEM Detector Readout with AWAGS - ASIC - First ^{238}U Beam Time Measurements -

P. Wiczorek

GSI Helmholtzzentrum fuer Schwerionenforschung GmbH
Experiment Electronics Department

March 2020

Outline

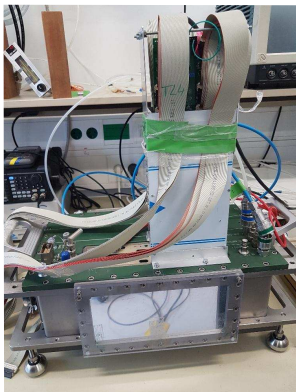
- 1 GEM Readout
- 2 Results
- 3 Summary

- Investigate the performance of the AWAGS - ASIC (Amplifier With Adaptive Gain Setting) as amplifier for the prototype of GEM detector
- Measurement goal: Verify if the developed charge sensitive amplifier can be used for the GEM detector readout
Identify noise, input charge, dynamic range, signal shape and how to handle with AWAGS amplifier

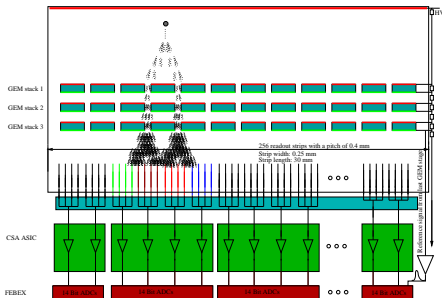
- Prototype of the GEM detector was only half equipped
- EEL developed a setup for PANDA and Super-FRS
 - Readout all 256 strips individually
 - Data taking with different ASIC gain settings
 - Measure different HV configurations
 - Determine the maximum event rate
- Data analysis: Determine position and find optimum for strip granularity and resolution

Outline

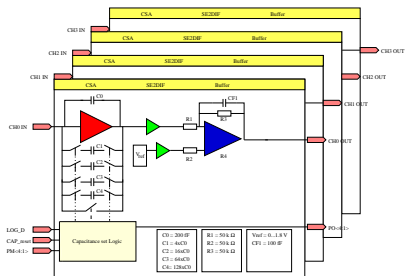
- 1 GEM Readout
 - GEM Prototype
 - Readout Electronics
 - Digitalization and DAQ
- 2 Results
- 3 Summary



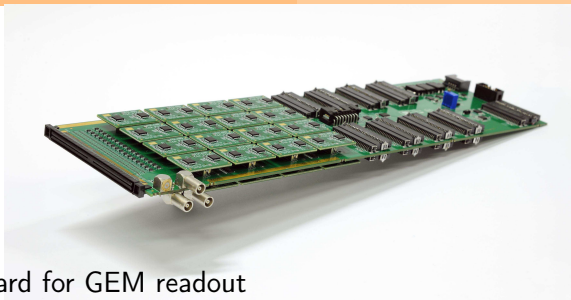
- SFRS prototype GEM detector
- Design: 2×256 strips
- Only half of the strips are read out during beamtime
- Strip pitch of $400 \mu\text{m}$
- GEM is built up in 3 stacks
- GEM geometry:
 $200 \times 100 \times 25 \text{ mm}^3$



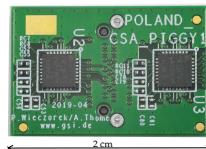
- Energy deposition by the beam in the drift region
- Charge drift in electrical field to the GEM stack
- Gas amplification due to the electrical field between GEM surfaces

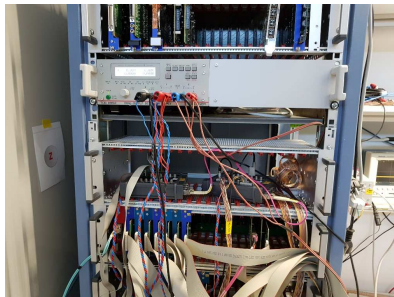
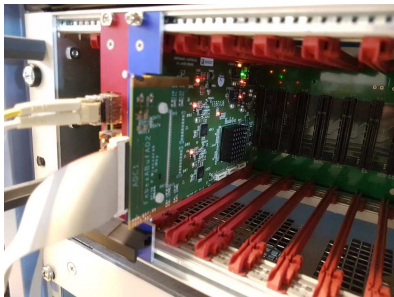


- FEE (Amplifier With Adaptive Gain Setting) AWAGS-ASIC
- 4 Channels per AWAGS-ASIC
- Charge sensitive input stage
- Single ended output buffer
- Not yet optimized for PANDA or SFERS setup
- 2 operation modes:
manual or auto feedback setting



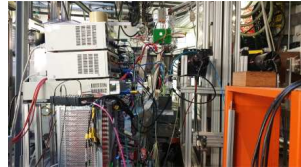
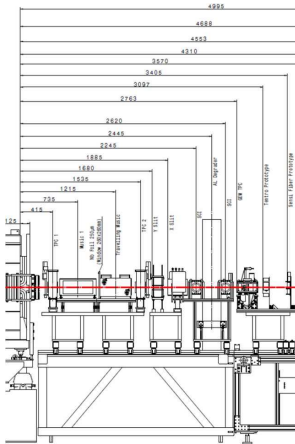
- Main board for GEM readout
- 32 plug-in boards with AWAGS-ASICs
- 2 AWAGS-ASICs per plug-in board
- Over all power (0.28 A at 12 V)
- Thanks to Sven Loechner (EEL)





- Digitizer FEBEX ADC cards
- 16 differential channels per FEBEX
- 14 bit, 50MS/s, input $\pm 1V$

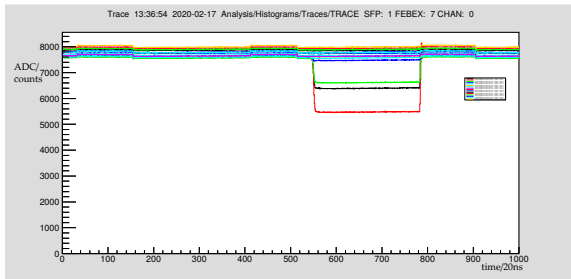
- Readout for 256 channels
- 16 FEBEX card
- Thanks N. Kurz (EEL)



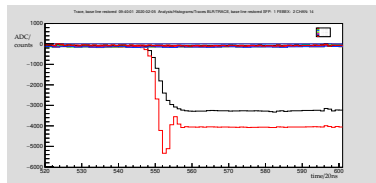
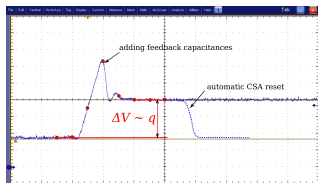
- Setup with 2 TPCs and 1 GEM
- Periodic reset: every 5 μs
reset time of 2 μs
- Reset is disabled after accepted trigger

Outline

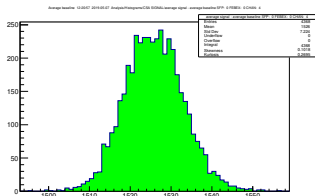
- 1 GEM Readout
- 2 Results
 - Trace Analysis
 - Noise Calculation
 - Dynamic Range
 - Leakage Current
 - Beamtime Results
- 3 Summary



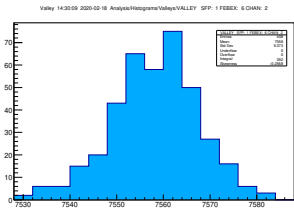
- Figure shows trace with length of 1000×20 ns
- Active reset 100×20 ns
- Manual Mode: fixed feedback capacitance
- Pulse height: $1/8$ mV per ADC count
results from 14 bit ADC and ± 1 V input range



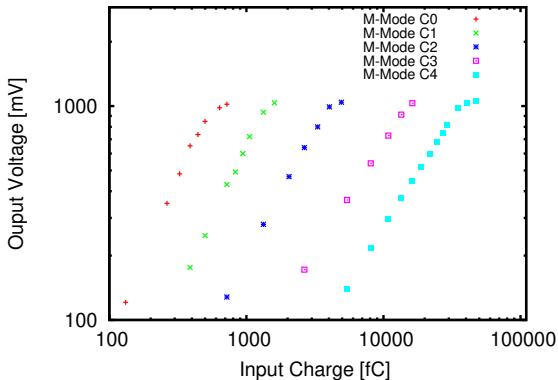
- Auto mode: adaptive gain setting
- Left figure: Test signal measured with an oscilloscope
- Right figure: signal taken during beam time 2019
 - Channel (black) below SW TH → only C_0 feedback is active
 - Channel (red) over SW TH → C_0 and C_1 feedback is active



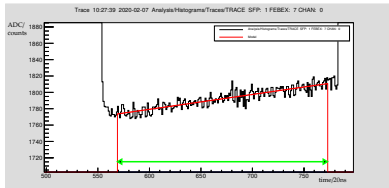
- Laboratory noise measurements (full setup, no beam)
- $ENC = (0.43 \pm 0.04)fC$ or $(2697 \pm 251)e^-$.



- Beamtime noise measurements (full setup beamtime 2019)
- $ENC = (0.56 \pm 0.052)fC$ or $(3502 \pm 321)e^-$.

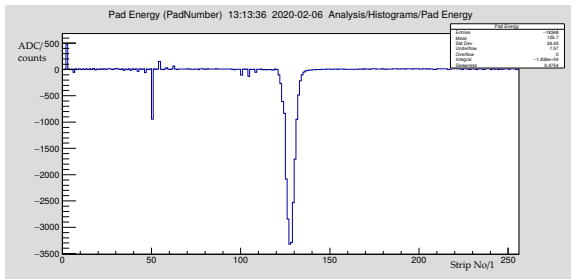


- Laboratory measurements for dynamic range
- Output voltage as function of input charge
- Max. input charge up to 40 pC



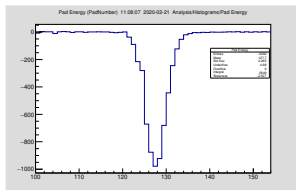
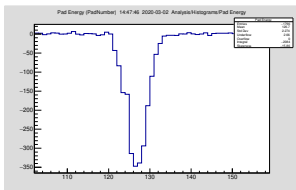
Cap. No.	Drift	Unit
C_0	8.94 ± 0.79	$\text{mV}/\mu\text{s}$
C_1	$3,28 \pm 0.15$	$\text{mV}/\mu\text{s}$
C_2	$0,925 \pm 0.051$	$\text{mV}/\mu\text{s}$
C_3	0.287 ± 0.026	$\text{mV}/\mu\text{s}$
C_4	$0,088 \pm 0.0031$	$\text{mV}/\mu\text{s}$

- Active reset topology has a drawback \rightarrow leakage current
- Each event shows a drift results from leakage current in the feedback switch
- Slope is proportional to the amplification

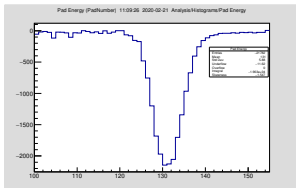


- Determine beam position
 - Plot the measured amplitude for 256 strips
 - All ASICs are programmed to the same amplification
- Special Thanks to the Go4 group especially to Nik Kurz and Joern Adamczewski-Musch for the analysis

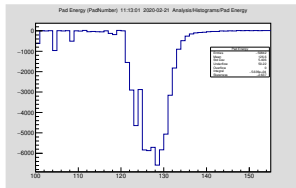
● Beam positions for different configurations and constant HV=3470V(Drift)/2300V(Stack)



● Feedback configuration: 15

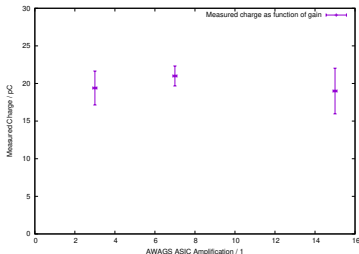


● Feedback configuration: 7

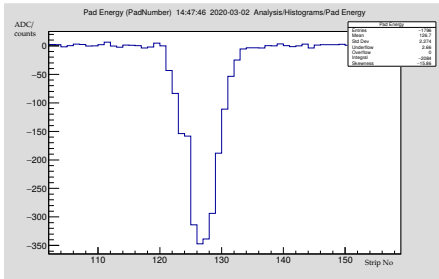


● Feedback configuration: 3

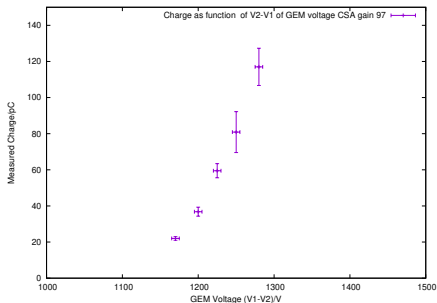
● Feedback configuration: 1



- Plot shows results for total charge measurements
 - Approximately 20 pC measured with all feedback configurations
 - Feedback config. 1 was not considered because of clipping
- Gain calculation of the GEM
 - SFRS sim. data: 835 MeV U^{238} -beam \rightarrow 200 fC/u in drift region
 - Gain of GEM detector:
 $Gain_{GEM} \approx 20 \text{ pC} / 200 \text{ fC} \approx 100$



- Lowest AWAGS-ASIC gain (config. 15): 0.0117mV/fC
- E.g. peak voltage of one strip: about $350\text{ counts}/8 = 44\text{mV} \rightarrow 3.7\text{pC}$
- Amplifier clipping starts at $> 5000\text{ ADC counts}$
- Max. input charge for one channel is $> 40\text{ pC}$



- GEM amplification vs high voltage
- Measured charge is between 20 pC and 120 pC
- Gain of the prototype GEM was between 100 - 600

Outline

- 1 GEM Readout
- 2 Results
- 3 **Summary**
 - Done
 - To Do
 - Open Questions

- First readout of a GEM prototype with AWAGS-ASIC in laboratory was done 2019
- Successful test with γ -source in July 2019
- Designed first prototype for 256 channel readout
- Successful beamtime December 2019
- Preliminary results from electronics are presented and are promising

- Calculate/analyse the position resolution with TPC - data from beamtime 2019
 - Get response for clustering of pads
 - Is the pitch of $400\ \mu\text{m}$ necessary? Higher clustering produces more charge but what about the resolution?
- Thanks to Klaus Götzen

- Event rate constrains
 - Beamtime 2019: kHz event rate
 - What is the event rate for the final design?
- Rise time
 - Dependency between GEM amplification and rise time was observed
 - Low GEM amplification (about 100) → risetime is about 120 ns
- PANDA: Rare U - beam
 - What about protons?! How many electrons per nucleon in drift region?
 - What is the required time and position resolution?
 - New beamtime with p with the existing setup?

Thanks to

T. Blatz, C. Caesar, D. Chokheli, F. García, T. Grahn, C.
Karagiannis, N. Kurz, S. Löchner, M. Luoma, S. Pietri, M.-M.
Schmidt, B. Voss, H. Weick, C. Nociforo and the FRS team

CSA No.	C_0	C_1	C_2	C_3	C_4	No. Cap.	Value/fC	Gain/mV/fC
0	1	0	0	0	0	1	200	2.5
1	1	1	0	0	0	5	1000	0.5
2	1	0	1	0	0	17	3400	0.1471
3	1	1	1	0	0	21	4200	0.1190
4	1	0	0	1	0	65	13000	0.0385
5	1	1	0	1	0	69	13800	0.0362
6	1	0	1	1	0	81	16200	0.0309
7	1	1	1	1	0	85	17000	0.0294
8	1	0	0	0	1	129	25800	0.0194
9	1	1	0	0	1	133	26600	0.0188
a	1	0	1	0	1	145	29000	0.0172
b	1	1	1	0	1	149	29800	0.0168
c	1	0	0	1	1	193	38600	0.0130
d	1	1	0	1	1	197	39400	0.0127
e	1	0	1	1	1	209	41800	0.0120
f	1	1	1	1	1	213	42600	0.0117